## Product Summary

| $BV_{DSS}$ | $R_{DS(ON)}$ Max | $I_D$ Max $T_A$ = +25°C |
|---|---|---|
| 30V | 59mΩ @ $V_{GS}$ = 10V | 2.9A |
| | 98mΩ @ $V_{GS}$ = 4.5V | 2.3A |

## Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

## Applications

- General-purpose interfacing switches
- Power management functions

## Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

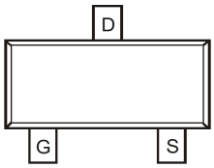
## Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)

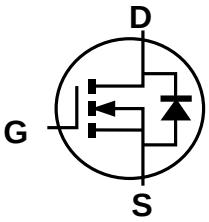
SOT23



Top View




Top View



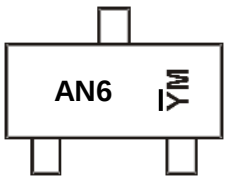

Equivalent Circuit

## Ordering Information (Note 4)

| Part Number | Package | Packing | |
|---|---|---|---|
| | | Qty. | Carrier |
| DMN3061S-7 | SOT23 | 3,000 | Tape & Reel |
| DMN3061S-13 | SOT23 | 10,000 | Tape & Reel |

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information




AN6 = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: J = 2022)
M = Month (ex: 8 = August)

Date Code Key

| Year | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | I | J | K | L | M | N | O | P | R | S | T | U |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |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## Maximum Ratings (@ $T_A$ = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|---|---|---|---|---|
| Drain-Source Voltage | | | $V_{DSS}$ | 30 | V |
| Gate-Source Voltage | | | $V_{GSS}$ | ±20 | V |
| Continuous Drain Current (Note 5) $V_{GS}$ = 4.5V | Steady State | $T_A$ = +25°C<br>$T_A$ = +70°C | $I_D$ | 2.3<br>1.8 | A |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | $I_S$ | 1.3 | A |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | | $I_{DM}$ | 24 | A |

## Thermal Characteristics (@ $T_A$ = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|---|---|---|
| Power Dissipation (Note 5) | $P_D$ | 0.77 | W |
| Thermal Resistance, Junction to Ambient @$T_A$ = +25°C (Note 5) | $R_{\theta JA}$ | 161 | °C/W |
| Power Dissipation (Note 6) | $P_D$ | 1.23 | W |
| Thermal Resistance, Junction to Ambient @$T_A$ = +25°C (Note 6) | $R_{\theta JA}$ | 101 | °C/W |
| Operating and Storage Temperature Range | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## Electrical Characteristics (@ $T_A$ = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---|---|---|---|---|---|
| **OFF CHARACTERISTICS** (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | 30 | — | — | V | $V_{GS}$ = 0V, $I_D$ = 250µA |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | — | — | 1.0 | µA | $V_{DS}$ = 24V, $V_{GS}$ = 0V |
| Gate-Source Leakage | $I_{GSS}$ | — | — | ±100 | nA | $V_{GS}$ = ±20V, $V_{DS}$ = 0V |
| **ON CHARACTERISTICS** (Note 7) | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | 0.5 | 1.3 | 1.8 | V | $V_{DS}$ = $V_{GS}$, $I_D$ = 250µA |
| Static Drain-Source On-Resistance | $R_{DS(ON)}$ | — | 28 | 59 | mΩ | $V_{GS}$ = 10V, $I_D$ = 3.1A |
| | | | 35 | 98 | | $V_{GS}$ = 4.5V, $I_D$ = 2A |
| | | | 45 | 196 | | $V_{GS}$ = 3.3V, $I_D$ = 1.5A |
| Diode Forward Voltage | $V_{SD}$ | — | 0.7 | 1.0 | V | $V_{GS}$ = 0V, $I_S$ = 1A |
| **DYNAMIC CHARACTERISTICS** (Note 8) | | | | | | |
| Input Capacitance | $C_{iss}$ | — | 233 | — | pF | $V_{DS}$ = 15V, $V_{GS}$ = 0V<br>f = 1.0MHz |
| Output Capacitance | $C_{oss}$ | — | 45 | — | pF | |
| Reverse Transfer Capacitance | $C_{rss}$ | — | 31 | — | pF | |
| Gate Resistance | $R_g$ | — | 5.6 | — | Ω | $V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1MHz |
| Total Gate Charge ($V_{GS}$ = 4.5V) | $Q_g$ | — | 2.9 | — | nC | $V_{DS}$ = 15V, $I_D$ = 3A |
| Total Gate Charge ($V_{GS}$ = 10V) | $Q_g$ | — | 5.5 | — | nC | |
| Gate-Source Charge | $Q_{gs}$ | — | 0.6 | — | nC | |
| Gate-Drain Charge | $Q_{gd}$ | — | 0.9 | — | nC | |
| Turn-On Delay Time | $t_{D(ON)}$ | — | 0.9 | — | ns | $V_{GS}$ = 10V, $V_{DS}$ = 15V<br>$R_G$ = 3Ω, $R_L$ = 1.7Ω |
| Turn-On Rise Time | $t_R$ | — | 2.8 | — | ns | |
| Turn-Off Delay Time | $t_{D(OFF)}$ | — | 10.0 | — | ns | |
| Turn-Off Fall Time | $t_F$ | — | 2.4 | — | ns | |

Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.


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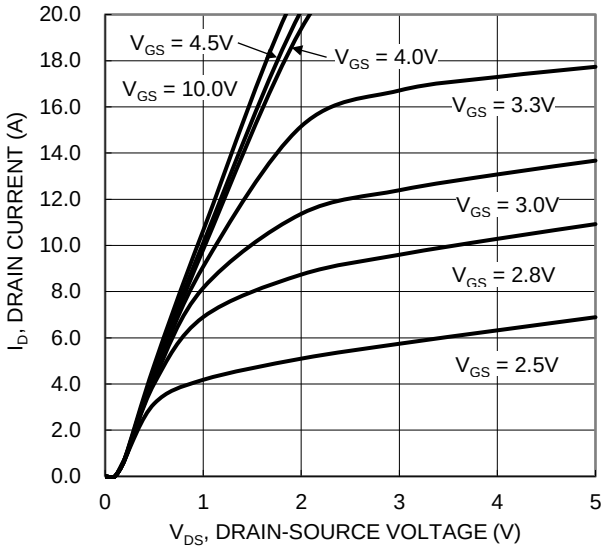


Figure 1. Typical Output Characteristic

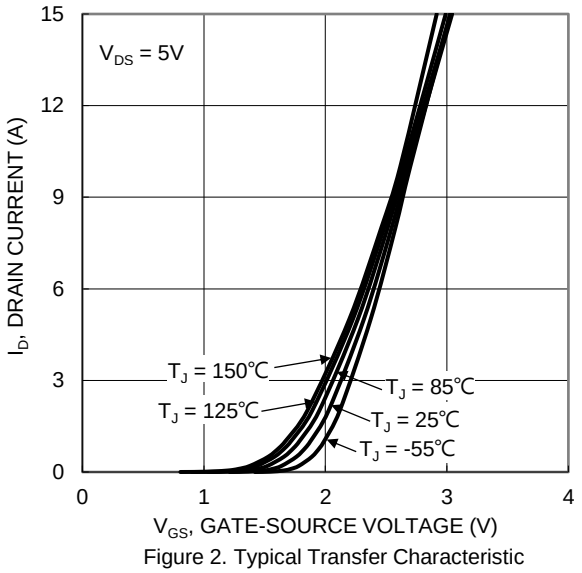


Figure 2. Typical Transfer Characteristic

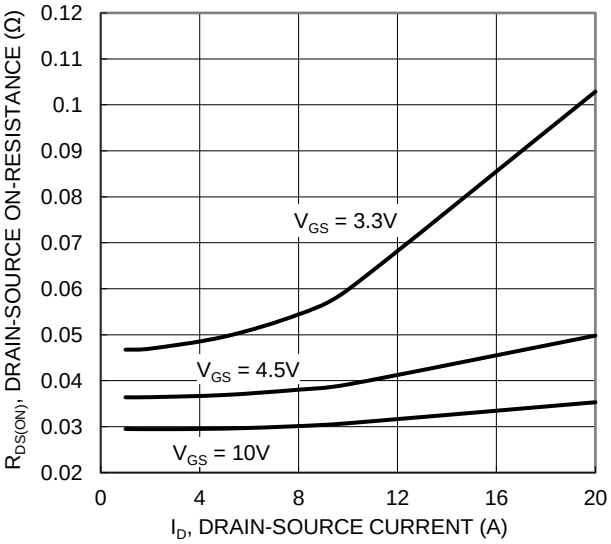


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

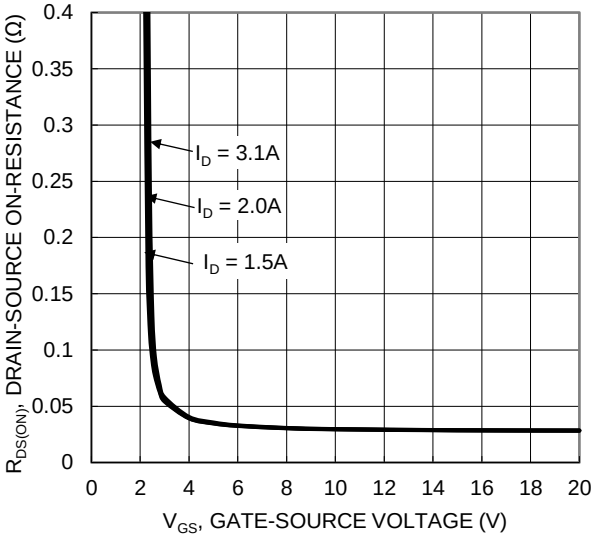


Figure 4. Typical Transfer Characteristic

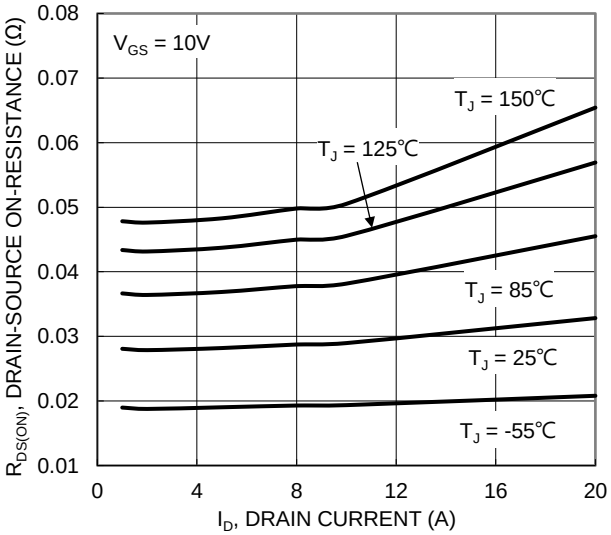


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

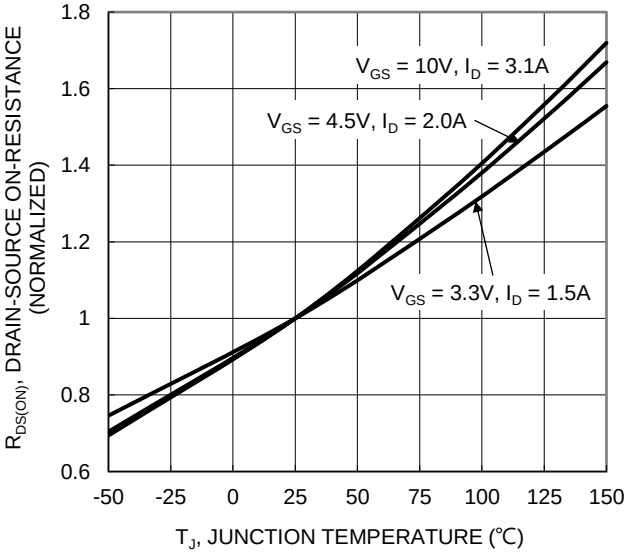


Figure 6. On-Resistance Variation with Junction Temperature


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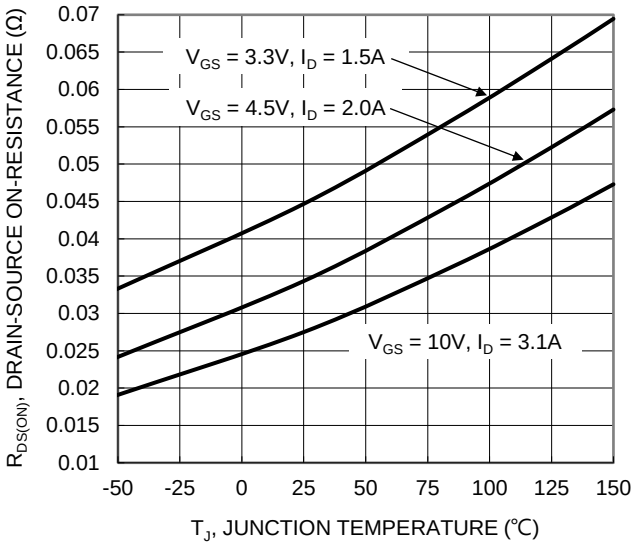


Figure 7. On-Resistance Variation with Junction Temperature

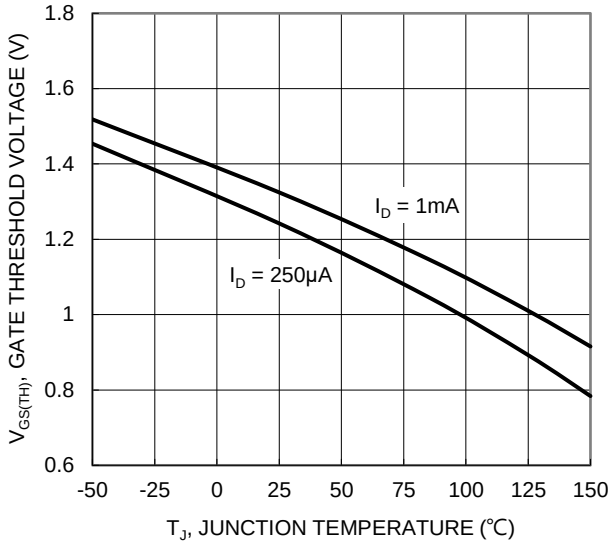


Figure 8. Gate Threshold Variation vs. Junction Temperature

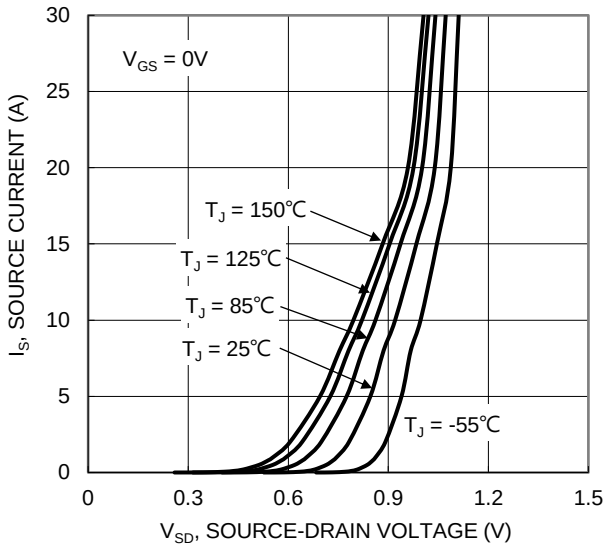


Figure 9. Diode Forward Voltage vs. Current

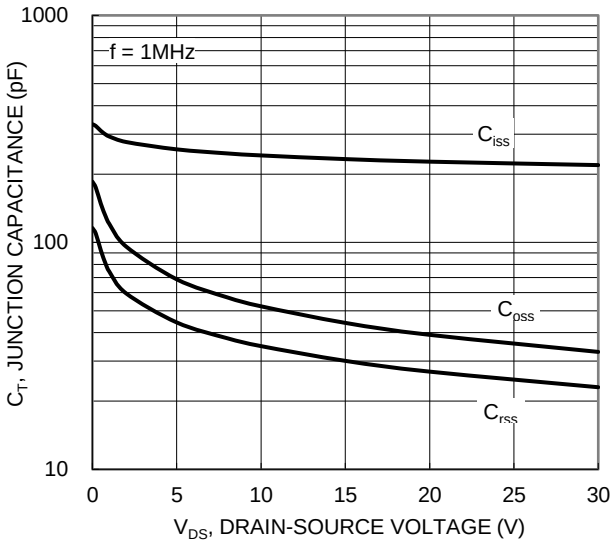


Figure 10. Typical Junction Capacitance

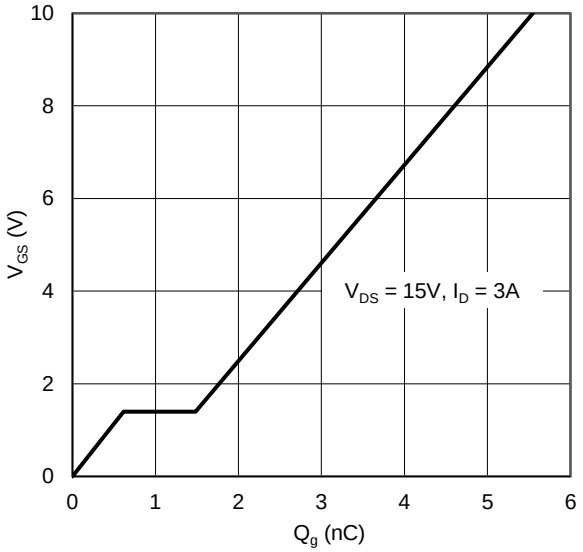


Figure 11. Gate Charge

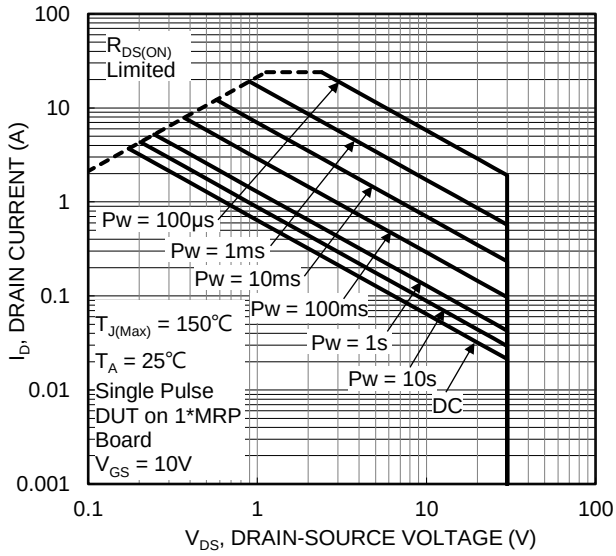


Figure 12. SOA, Safe Operation Area


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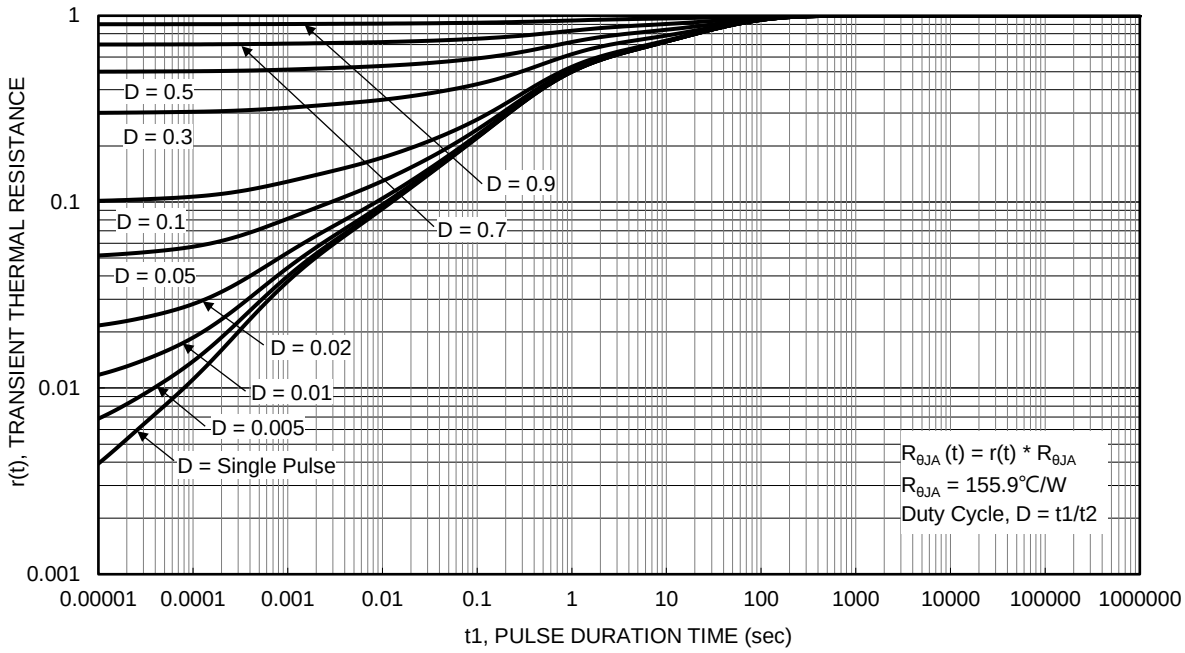


Figure 13. Transient Thermal Resistance


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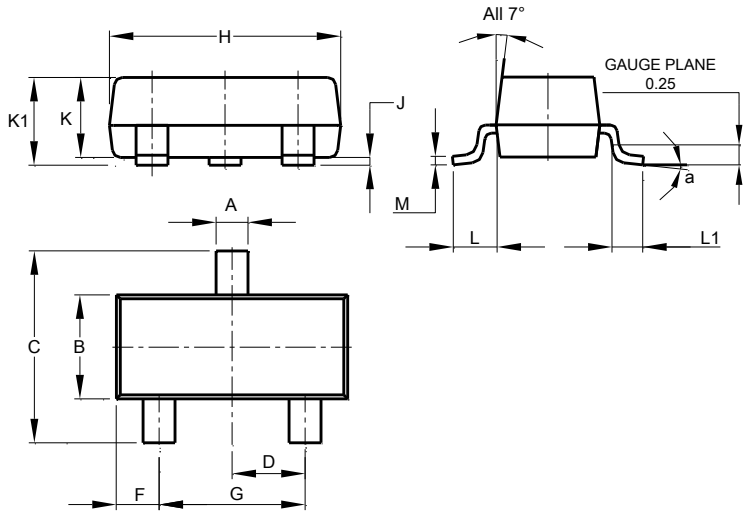
## Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SOT23**

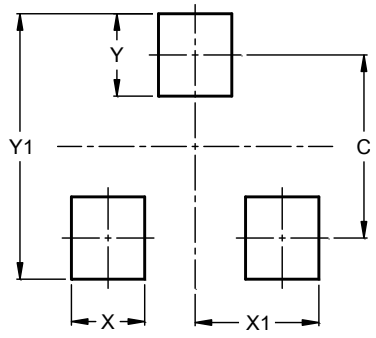



| SOT23 | | | |
|---|---|---|---|
| **Dim** | **Min** | **Max** | **Typ** |
| **A** | 0.37 | 0.51 | 0.40 |
| **B** | 1.20 | 1.40 | 1.30 |
| **C** | 2.30 | 2.50 | 2.40 |
| **D** | 0.89 | 1.03 | 0.915 |
| **F** | 0.45 | 0.60 | 0.535 |
| **G** | 1.78 | 2.05 | 1.83 |
| **H** | 2.80 | 3.00 | 2.90 |
| **J** | 0.013 | 0.10 | 0.05 |
| **K** | 0.890 | 1.00 | 0.975 |
| **K1** | 0.903 | 1.10 | 1.025 |
| **L** | 0.45 | 0.61 | 0.55 |
| **L1** | 0.25 | 0.55 | 0.40 |
| **M** | 0.085 | 0.150 | 0.110 |
| **a** | 0° | 8° | -- |
| **All Dimensions in mm** | | | |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SOT23**




| Dimensions | Value (in mm) |
|---|---|
| **C** | 2.0 |
| **X** | 0.8 |
| **X1** | 1.35 |
| **Y** | 0.9 |
| **Y1** | 2.9 |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